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# FACSIMILE COVER SHEET

To: Examiner Khiem D. Nguyen

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April 6, 2006

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Tseng

Docket No.:

TSM03-0763

Serial No:

10/828,884

Art Unit:

2823

Date Filed:

April 21, 2004

Title:

Compensated Linearity Voltage-Control-Capacitor Device by Standard CMOS

**Process** 

## CERTIFICATION OF FACSIMILE TRANSMISSION

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- Certification of Facsimile Transmission (1 page)
- Election (1 page)

Respectfully submitted,

sty Engeldahl Legal Assistant

Confirmation Respectfully Requested

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For:

Compensated Linearity Voltage-Control-Capacitor Device by Standard

**CMOS Process** 

Mail Stop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

## **ELECTION**

Dear Sir:

In response to the restriction requirement set forth in the Office Action mailed on March 14, 2006, Applicant elects claims 1-19 with traverse for further prosecution in the above patent application. The claims of Group I are directed to a method of forming a semiconductor device, and the claims of Group II are directed to a semiconductor device. Thus, even though Group I is directed to a method and Group II is directed to a device formed by the method, the claims of Group I and Group II are closely related such that examination of both groups would not pose an undue burden on the Examiner.

Respectfully submitted,

Ce april 2006

James C. Kestersón Attorney for Applicant

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